

May 2016

US1AFA - US1MFA Super Fast Surface Mount Rectifiers

Features

- · Glass Passivated Chip Junction
- · Low Power Loss, High Efficiency
- Fast Switching Reverse Recovery Time: 50~75 ns Maximum
- · High Surge Capacity
- UL Flammability 94V-0 Classification
- MSL 1 per J-STD-020
- RoHS Compliant / Green Molding Compound
- Industrial Device Qualified per AEC-Q101 Standards
 - * See authorized use policy



SOD-123FA

Cathode



Anode

Ordering Information

Part Number	Top Mark	Package	Packing Method
US1AFA	HAL	SOD-123FA	Tape and Reel
US1BFA	HBL	SOD-123FA	Tape and Reel
US1DFA	HDL	SOD-123FA	Tape and Reel
US1FFA	HFL	SOD-123FA	Tape and Reel
US1GFA	HGL	SOD-123FA	Tape and Reel
US1JFA	HJL	SOD-123FA	Tape and Reel
US1KFA	HKL	SOD-123FA	Tape and Reel
US1MFA	HML	SOD-123FA	Tape and Reel

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25$ °C unless otherwise noted.

	Parameter		Value								
Symbol			US1 BFA	US1 DFA	US1 FFA	US1 GFA	US1 JFA	US1 KFA	US1 MFA	Unit	
V _{RRM}	Repetitive Peak Reverse Voltage	50	100	200	300	400	600	800	1000	V	
V _{RMS}	RMS Reverse Voltage	35	70	140	210	280	420	560	700	V	
V _R	DC Blocking Voltage	50	100	200	300	400	600	800	1000	V	
I _{F(AV)}	Average Forward Rectified Current			1							
I _{FSM}	Peak Forward Surge Current: 8.3 ms Single Half Sine-Wave Superimposed on Rated Load			30						Α	
T _J	Operating Junction Temperature Range			-55 to +150							
T _{STG}	Storage Temperature Range			-55 to +150						°C	

Thermal Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Value	Unit
ΨJL	Typical Thermal Characteristics, Junction-to-Lead	21	°C/W
$R_{ heta JA}$	Typical Thermal Resistance, Junction-to-Ambient	153	°C/W

Note:

1. Device mounted at minimum pad.

Electrical Characteristics

Values are at T_A = 25°C unless otherwise noted.

	Parameter	Conditions	Value								
Symbol			US1 AFA	US1 BFA	US1 DFA	US1 FFA	US1 GFA	US1 JFA	US1 KFA	US1 MFA	Unit
V _F	Maximum Instantaneous Forward Voltage ⁽²⁾	I _F = 1 A	0.95				1.30	1.70			٧
I _R	Maximum Reverse	$T_J = 25^{\circ}C$	5								
	Current at Rated V _R	$T_J = 125^{\circ}C$	150								μА
CJ	Typical Junction Capacitance	V _R = 4 V, f = 1 MHz	20 15						pF		
T _{rr}	Maximum Reverse Recovery Time	$I_F = 0.5 A,$ $I_R = 1 A,$ $I_{rr} = 0.25 A$	50 75						ns		

Note:

2. Pulse test with PW = $300 \mu s$, 1% duty cycle

Typical Performance Characteristics

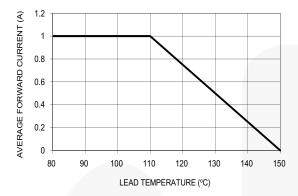


Figure 1. Maximum Forward Current Derating Voltage

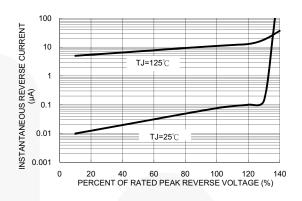


Figure 2. Typical Reverse Characteristics

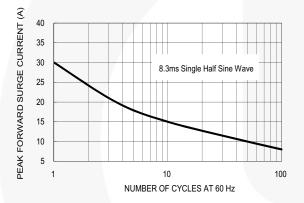


Figure 3. Maximum Non-Repetitive Forward Surge Current

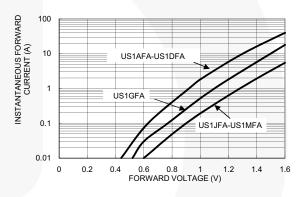


Figure 4. Typical Instantaneous Forward Characteristics

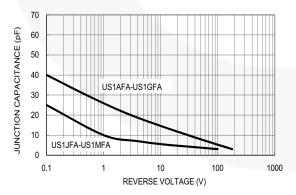


Figure 5. Typical Junction Capacitance

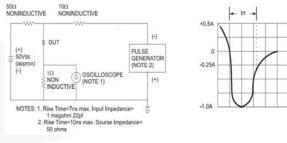
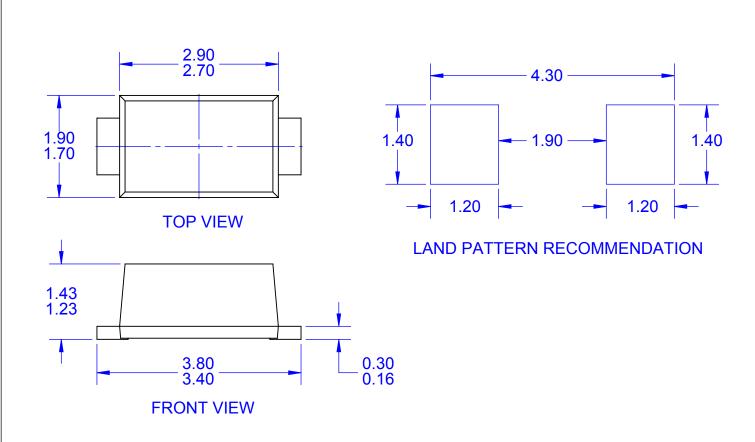
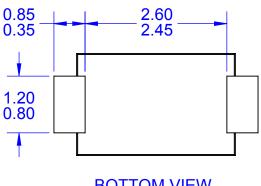


Figure 6. Reverse Recovery Time Characteristic and Test Circuit Diagram





BOTTOM VIEW

NOTES:

- A. NO INDUSTRY STANDARD APPLIES TO THIS PACKAGE.
- B. ALL DIMENSIONS ARE IN MILLIMETERS. C. DIMENSIONS ARE EXCLUSIVE OF BURRS MOLD FLASH AND TIE BAR PROTRUSIONS.
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